The HMC460 is a GaAs MMIC PHEMT Low Noise Distributed Amplifier die which operates between DC and 20 GHz. The amplifier provides 14 dB of gain, 2.5 dB noise figure and +16 dBm of output power at 1 dB gain compression while requiring only 60 mA from a +8V supply. The HMC460 amplifier can easily be integrated into Multi-Chip-Modules (MCMs) due to its small size. All data is with the chip in a 50 Ohm test fixture connected via 0.025mm (1 mil) diameter wire bonds of minimal length 0.31mm (12 mils).

**Features**
- Noise Figure: 2.5 dB @ 10 GHz
- Gain: 14 dB @ 10 GHz
- P1dB Output Power: +16 dBm @ 10 GHz
- Supply Voltage: +8V @ 60 mA
- 50 Ohm Matched Input/Output
- Die Size: 3.12 x 1.63 x 0.1 mm

**Typical Applications**
- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation

**Electrical Specifications, \( T_A = +25^\circ C, Vdd= 8V, Idd= 60 mA^* \)**

<table>
<thead>
<tr>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td>Frequency Range</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>GHz</td>
</tr>
<tr>
<td>Gain</td>
<td>12</td>
<td>14</td>
<td>12</td>
<td>14</td>
<td>11</td>
<td>13</td>
<td></td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Gain Flatness</td>
<td>± 0.5</td>
<td>± 0.15</td>
<td>± 0.25</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Gain Variation Over Temperature</td>
<td>0.008</td>
<td>0.016</td>
<td>0.01</td>
<td>0.02</td>
<td>0.01</td>
<td>0.02</td>
<td></td>
<td></td>
<td></td>
<td>dB/ °C</td>
</tr>
<tr>
<td>Noise Figure</td>
<td>4.0</td>
<td>5.0</td>
<td>2.5</td>
<td>3.5</td>
<td>3.0</td>
<td>4.0</td>
<td></td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Input Return Loss</td>
<td>17</td>
<td></td>
<td>22</td>
<td></td>
<td>15</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Output Return Loss</td>
<td>17</td>
<td></td>
<td>15</td>
<td></td>
<td>15</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Output Power for 1 dB Compression ( P1dB )</td>
<td>14</td>
<td>17</td>
<td>13</td>
<td>16</td>
<td>12</td>
<td>15</td>
<td></td>
<td></td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td>Saturated Output Power ( Psat )</td>
<td>18</td>
<td></td>
<td>18</td>
<td></td>
<td>17</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td>Output Third Order Intercept ( IP3 )</td>
<td>27.5</td>
<td></td>
<td>28</td>
<td></td>
<td>27</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td>Supply Current ( Idd ) ( Vdd= 8V, Vgg1= -0.9V Typ. )</td>
<td>60</td>
<td></td>
<td>60</td>
<td></td>
<td>60</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>mA</td>
</tr>
</tbody>
</table>

* Adjust Vgg between -2 to 0V to achieve Idd= 60 mA typical.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

Downloaded from Arrow.com.
HMC460
GaAs PHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

**Output P1dB vs. Temperature**

**Psat vs. Temperature**

**Output IP3 vs. Temperature**

**Gain, Power & Noise Figure vs. Supply Voltage @ 10 GHz, Fixed Vgg1**

**Reverse Isolation vs. Temperature**

**Additive Phase Noise Vs Offset Frequency, RF Frequency = 10 GHz, RF Input Power = 9 dBm (Psat)**

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106
Phone: 781-329-4700 • Order online at www.analog.com
Application Support: Phone: 1-800-ANALOG-D
**Absolute Maximum Ratings**

- Drain Bias Voltage (Vdd): +9 Vdc
- Gate Bias Voltage (Vgg): -2 to 0 Vdc
- Gate Bias Voltage (Igg): 2.5 mA
- RF Input Power (RFIN\(\text{Vdd} = +8\) Vdc): +18 dBm
- Channel Temperature: 175 °C
- Continuous Pdiss (T = 85 °C) (derate 24 mW/°C above 85 °C): 2.17 W
- Thermal Resistance (channel to die bottom): 41.5 °C/W
- Storage Temperature: -65 to +150 °C
- Operating Temperature: -55 to +85 °C
- ESD Sensitivity (HBM): Class 1A

**Typical Supply Current vs. Vdd**

<table>
<thead>
<tr>
<th>Vdd (V)</th>
<th>Idd (mA)</th>
</tr>
</thead>
<tbody>
<tr>
<td>+7.5</td>
<td>59</td>
</tr>
<tr>
<td>+8.0</td>
<td>60</td>
</tr>
<tr>
<td>+8.5</td>
<td>62</td>
</tr>
</tbody>
</table>

**Die Packaging Information**

<table>
<thead>
<tr>
<th>Standard</th>
<th>Alternate</th>
</tr>
</thead>
<tbody>
<tr>
<td>GP-1 (Gel Pack)</td>
<td>[2]</td>
</tr>
</tbody>
</table>

[1] Refer to the "Packaging Information" section for die packaging dimensions.


**NOTES:**
1. ALL DIMENSIONS IN INCHES [MILLIMETERS]
2. NO CONNECTION REQUIRED FOR UNLABELED BOND PADS
3. DIE THICKNESS IS 0.004 (0.100)
4. TYPICAL BOND PAD IS 0.004 (0.100) SQUARE
5. BACKSIDE METALLIZATION: GOLD
6. BACKSIDE METAL IS GROUND
7. BOND PAD METALIZATION: GOLD

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106
Phone: 781-329-4700 • Order online at www.analog.com
Application Support: Phone: 1-800-ANALOG-D
### Pad Descriptions

<table>
<thead>
<tr>
<th>Pad Number</th>
<th>Function</th>
<th>Description</th>
<th>Pin Schematic</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>RFIN</td>
<td>This pad is DC coupled and matched to 50 Ohms.</td>
<td><img src="image1" alt="RFIN Pin Schematic" /></td>
</tr>
<tr>
<td>2</td>
<td>Vdd</td>
<td>Power supply voltage for the amplifier. External bypass capacitors are required</td>
<td><img src="image2" alt="Vdd Pin Schematic" /></td>
</tr>
<tr>
<td>3</td>
<td>ACG1</td>
<td>Low frequency termination. Attach bypass capacitor per application circuit herein.</td>
<td><img src="image3" alt="ACG1 Pin Schematic" /></td>
</tr>
<tr>
<td>4</td>
<td>RFOUT</td>
<td>This pad is DC coupled and matched to 50 Ohms.</td>
<td><img src="image4" alt="RFOUT Pin Schematic" /></td>
</tr>
<tr>
<td>5</td>
<td>ACG2</td>
<td>Low frequency termination. Attach bypass capacitor per application circuit herein.</td>
<td><img src="image5" alt="ACG2 Pin Schematic" /></td>
</tr>
<tr>
<td>6</td>
<td>Vgg</td>
<td>Gate control for amplifier. Adjust to achieve Idd= 60 mA.</td>
<td><img src="image6" alt="Vgg Pin Schematic" /></td>
</tr>
<tr>
<td>Die Bottom</td>
<td>GND</td>
<td>Die bottom must be connected to RF/DC ground.</td>
<td><img src="image7" alt="GND Pin Schematic" /></td>
</tr>
</tbody>
</table>
Mounting & Bonding Techniques for Millimeterwave GaAs MMICs

The die should be attached directly to the ground plane eutectically or with conductive epoxy (see HMC general Handling, Mounting, Bonding Note). 50 Ohm Microstrip transmission lines on 0.127mm (5 mil) thick alumina thin film substrates are recommended for bringing RF to and from the chip (Figure 1). If 0.254mm (10 mil) thick alumina thin film substrates must be used, the die should be raised 0.150mm (6 mils) so that the surface of the die is coplanar with the surface of the substrate. One way to accomplish this is to attach the 0.102mm (4 mil) thick die to a 0.150mm (6 mil) thick molybdenum heat spreader (moly-tab) which is then attached to the ground plane (Figure 2).

Microstrip substrates should be located as close to the die as possible in order to minimize bond wire length. Typical die-to-substrate spacing is 0.076mm to 0.152 mm (3 to 6 mils).

Handling Precautions

Follow these precautions to avoid permanent damage.

Storage: All bare die are placed in either Waffle or Gel based ESD protective containers, and then sealed in an ESD protective bag for shipment. Once the sealed ESD protective bag has been opened, all die should be stored in a dry nitrogen environment.

Cleanliness: Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.

Static Sensitivity: Follow ESD precautions to protect against > ± 250V ESD strikes.

Transients: Suppress instrument and bias supply transients while bias is applied. Use shielded signal and bias cables to minimize inductive pick-up.

General Handling: Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers. The surface of the chip may have fragile air bridges and should not be touched with vacuum collet, tweezers, or fingers.

Mounting

The chip is back-metallized and can be die mounted with AuSn eutectic preforms or with electrically conductive epoxy. The mounting surface should be clean and flat.

Eutectic Die Attach: A 80/20 gold tin preform is recommended with a work surface temperature of 255 °C and a tool temperature of 265 °C. When hot 90/10 nitrogen/hydrogen gas is applied, tool tip temperature should be 290 °C. DO NOT expose the chip to a temperature greater than 320 °C for more than 20 seconds. No more than 3 seconds of scrubbing should be required for attachment.

Epoxy Die Attach: Apply a minimum amount of epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip once it is placed into position. Cure epoxy per the manufacturer’s schedule.

Wire Bonding

Ball or wedge bond with 0.025mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31mm (12 mils).
HMC460

GaAs PHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

Notes:

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106
Phone: 781-329-4700 • Order online at www.analog.com
Application Support: Phone: 1-800-ANALOG-D

Downloaded from Arrow.com.